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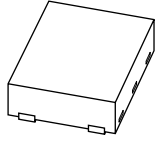
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Kind regards,

Team Nexperia



# PMEG3020EPA

2 A low  $V_F$  MEGA Schottky barrier rectifier

Rev. 01 — 15 December 2009

Product data sheet

## 1. Product profile

### 1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection. PMEG3020EPA is encapsulated in an ultra thin SOT1061 leadless small Surface-Mounted Device (SMD) plastic package with medium power capability.

### 1.2 Features

- Average forward current:  $I_{F(AV)} \leq 2$  A
- Reverse voltage:  $V_R \leq 30$  V
- Low forward voltage
- Exposed heat sink (cathode pad) for excellent thermal and electrical conductivity
- Leadless small SMD plastic package with medium power capability
- AEC-Q101 qualified

### 1.3 Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch Mode Power Supply (SMPS)
- Reverse polarity protection
- Low power consumption applications
- Battery chargers for mobile equipment

### 1.4 Quick reference data

**Table 1. Quick reference data**

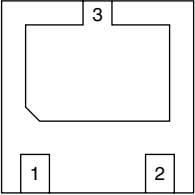

$T_j = 25$  °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$I_{F(AV)}$	average forward current	square wave; $\delta = 0.5$ ; $f = 20$ kHz				
		$T_{amb} \leq 65$ °C	[1]	-	2	A
		$T_{sp} \leq 140$ °C	-	-	2	A
$V_R$	reverse voltage		-	-	30	V
$V_F$	forward voltage	$I_F = 2$ A	-	410	470	mV
$I_R$	reverse current	$V_R = 30$ V	-	435	2500	$\mu$ A

[1] Device mounted on a ceramic Printed-Circuit Board (PCB),  $Al_2O_3$ , standard footprint.

## 2. Pinning information

**Table 2. Pinning**

Pin	Description	Simplified outline	Graphic symbol
1	anode	 <p>Transparent top view</p>	 006aab624
2	anode		
3	cathode		

## 3. Ordering information

**Table 3. Ordering information**

Type number	Package		
	Name	Description	Version
PMEG3020EPA	HUSON3	plastic thermal enhanced ultra thin small outline package; no leads; three terminals; body 2 × 2 × 0.65 mm	SOT1061

## 4. Marking

**Table 4. Marking codes**

Type number	Marking code
PMEG3020EPA	A2

## 5. Limiting values

**Table 5. Limiting values**

*In accordance with the Absolute Maximum Rating System (IEC 60134).*

Symbol	Parameter	Conditions	Min	Max	Unit	
$V_R$	reverse voltage	$T_j = 25\text{ °C}$	-	30	V	
$I_{F(AV)}$	average forward current	square wave; $\delta = 0.5$ ; $f = 20\text{ kHz}$				
		$T_{amb} \leq 65\text{ °C}$	[1]	-	2	A
		$T_{sp} \leq 140\text{ °C}$	-	-	2	A
$I_{FRM}$	repetitive peak forward current	$t_p \leq 1\text{ ms}$ ; $\delta \leq 0.25$	[2]	-	7	A
$I_{FSM}$	non-repetitive peak forward current	square wave; $t_p = 8\text{ ms}$	[2][3]	-	17	A
$P_{tot}$	total power dissipation	$T_{amb} \leq 25\text{ °C}$	[4][5]	-	500	mW
			[4][6]	-	960	mW
			[4][1]	-	1800	mW

**Table 5. Limiting values ...continued**  
*In accordance with the Absolute Maximum Rating System (IEC 60134).*

Symbol	Parameter	Conditions	Min	Max	Unit
$T_j$	junction temperature		-	150	°C
$T_{amb}$	ambient temperature		-55	+150	°C
$T_{stg}$	storage temperature		-65	+150	°C

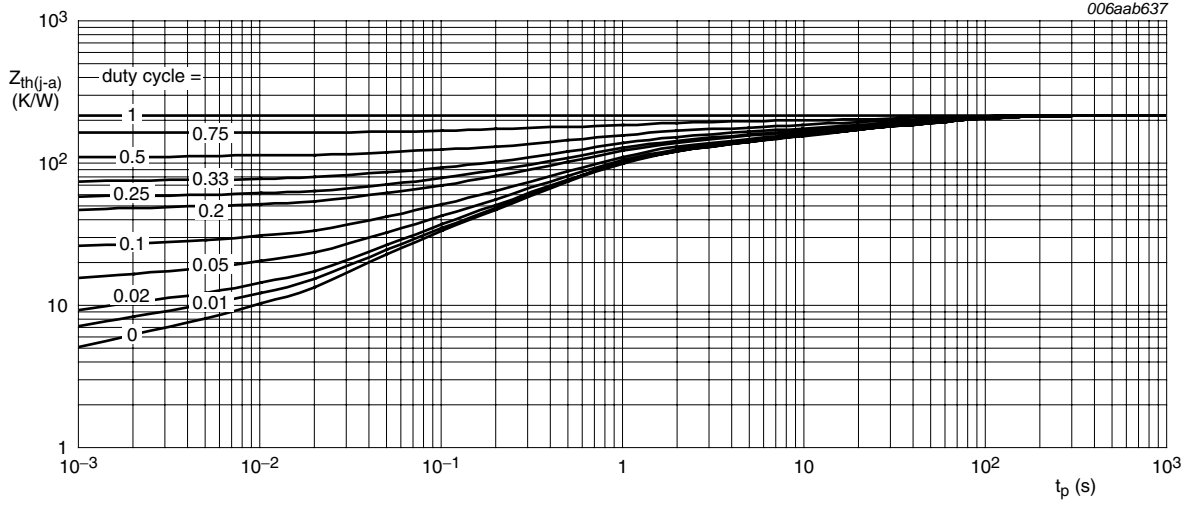
- [1] Device mounted on a ceramic PCB,  $Al_2O_3$ , standard footprint.  
 [2] Both anode pins connected.  
 [3]  $T_j = 25$  °C prior to surge.  
 [4] Reflow soldering is the only recommended soldering method.  
 [5] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.  
 [6] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

## 6. Thermal characteristics

**Table 6. Thermal characteristics**

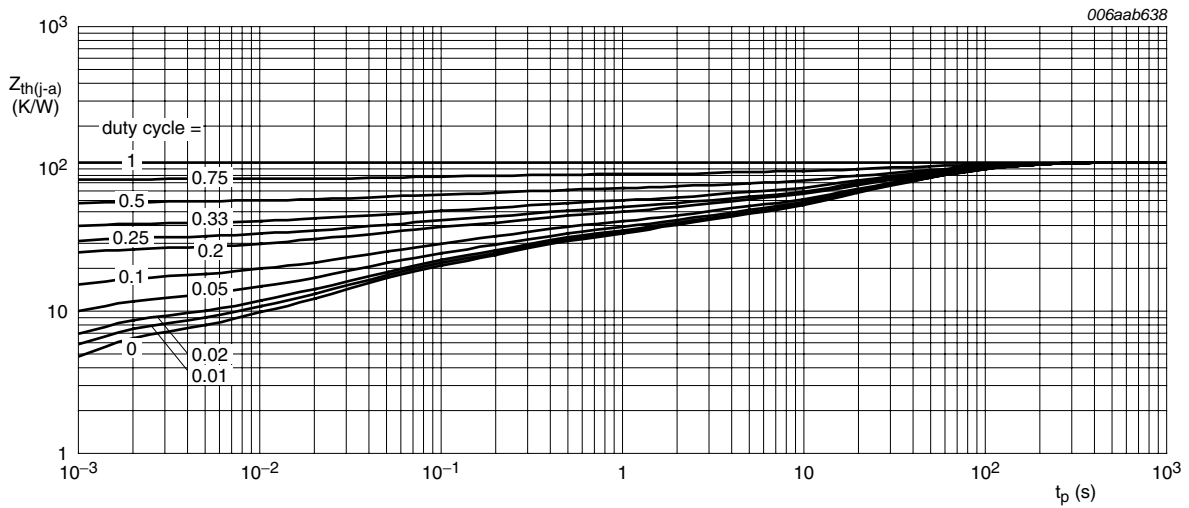
Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1][2]				
			[3]	-	-	250	K/W
			[4]	-	-	130	K/W
			[5]	-	-	70	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		[6]	-	-	12	K/W

- [1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses  $P_R$  are a significant part of the total power losses.  
 [2] Reflow soldering is the only recommended soldering method.  
 [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.  
 [4] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.  
 [5] Device mounted on a ceramic PCB,  $Al_2O_3$ , standard footprint.  
 [6] Soldering point of cathode tab.



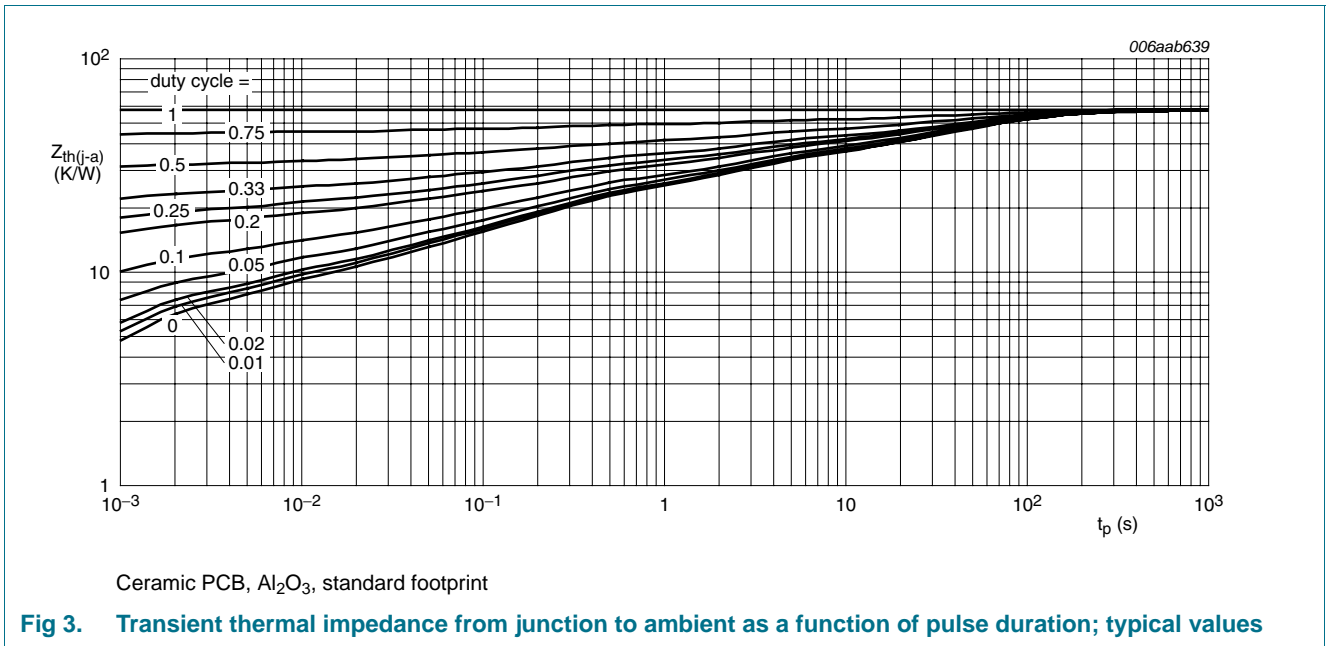
FR4 PCB, standard footprint

**Fig 1. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values**



FR4 PCB, mounting pad for cathode  $1 \text{ cm}^2$

**Fig 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values**



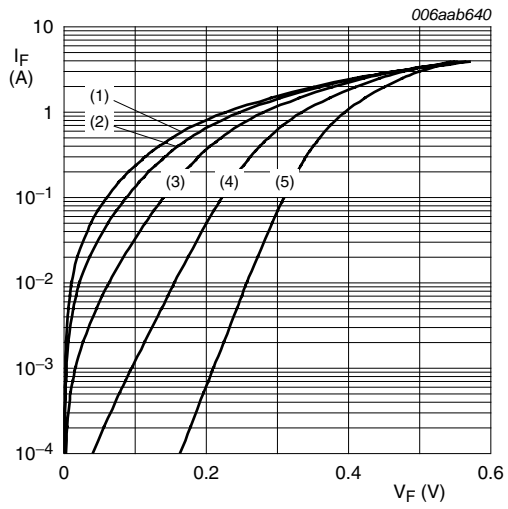
## 7. Characteristics

**Table 7. Characteristics**

$T_j = 25\text{ }^\circ\text{C}$  unless otherwise specified.

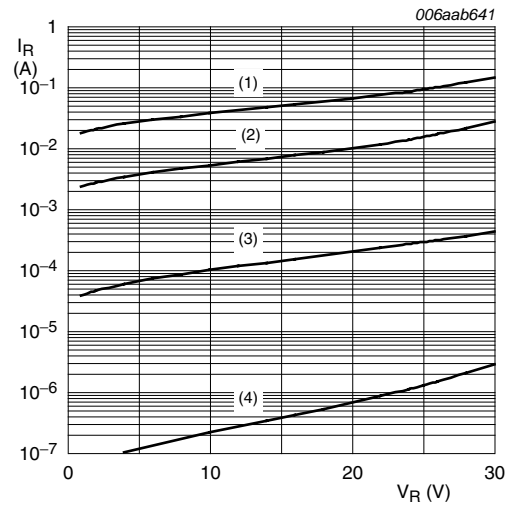
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_F$	forward voltage	$I_F = 0.5\text{ A}$	-	290	-	mV
		$I_F = 1\text{ A}$	-	335	-	mV
		$I_F = 2\text{ A}$	-	410	470	mV
$I_R$	reverse current	$V_R = 10\text{ V}$	-	100	-	$\mu\text{A}$
		$V_R = 30\text{ V}$	-	435	2500	$\mu\text{A}$
$C_d$	diode capacitance	$f = 1\text{ MHz}$				
		$V_R = 1\text{ V}$	-	150	-	pF
		$V_R = 10\text{ V}$	-	55	-	pF
$t_{rr}$	reverse recovery time		[1]	47	-	ns

[1] When switched from  $I_F = 10\text{ mA}$  to  $I_R = 10\text{ mA}$ ;  $R_L = 100\ \Omega$ ; measured at  $I_R = 1\text{ mA}$ .



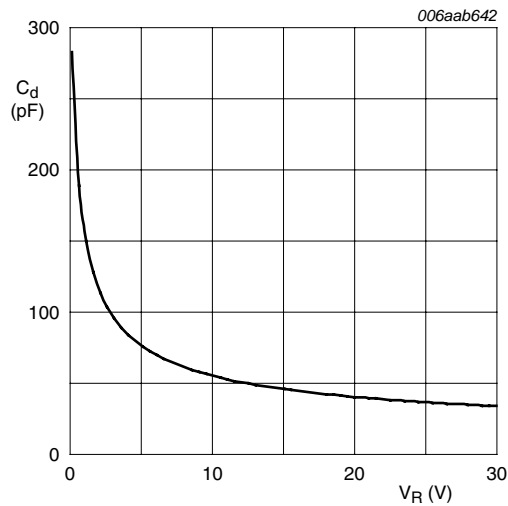
- (1)  $T_j = 150\text{ °C}$
- (2)  $T_j = 125\text{ °C}$
- (3)  $T_j = 85\text{ °C}$
- (4)  $T_j = 25\text{ °C}$
- (5)  $T_j = -40\text{ °C}$

**Fig 4. Forward current as a function of forward voltage; typical values**



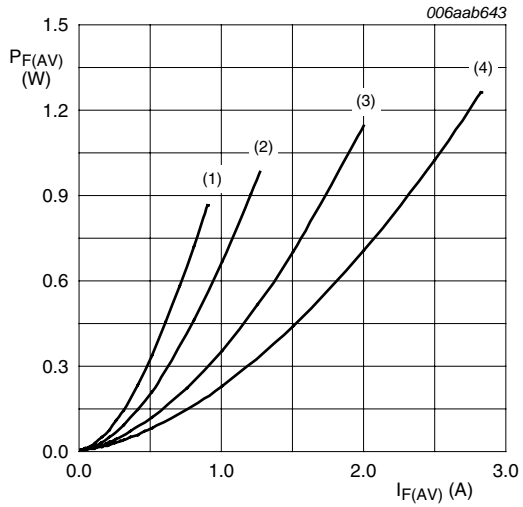
- (1)  $T_j = 125\text{ °C}$
- (2)  $T_j = 85\text{ °C}$
- (3)  $T_j = 25\text{ °C}$
- (4)  $T_j = -40\text{ °C}$

**Fig 5. Reverse current as a function of reverse voltage; typical values**



$f = 1\text{ MHz}; T_{amb} = 25\text{ °C}$

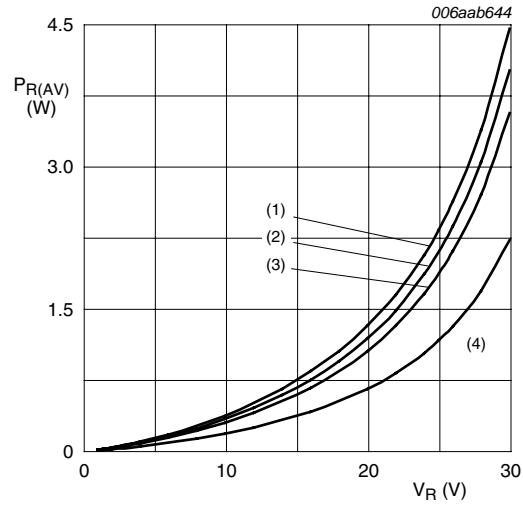
**Fig 6. Diode capacitance as a function of reverse voltage; typical values**



$T_j = 150\text{ °C}$

- (1)  $\delta = 0.1$
- (2)  $\delta = 0.2$
- (3)  $\delta = 0.5$
- (4)  $\delta = 1$

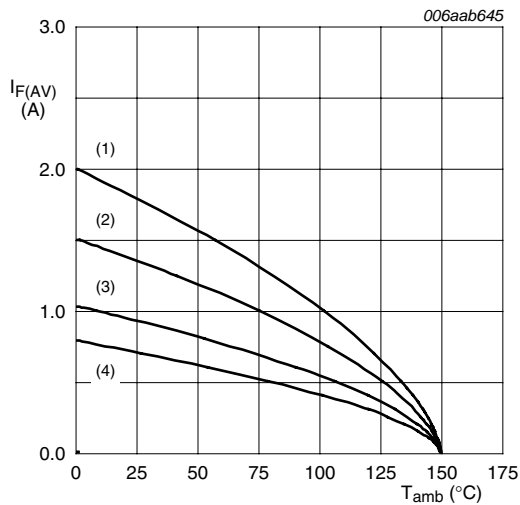
**Fig 7. Average forward power dissipation as a function of average forward current; typical values**



$T_j = 125\text{ °C}$

- (1)  $\delta = 1$
- (2)  $\delta = 0.9$
- (3)  $\delta = 0.8$
- (4)  $\delta = 0.5$

**Fig 8. Average reverse power dissipation as a function of reverse voltage; typical values**

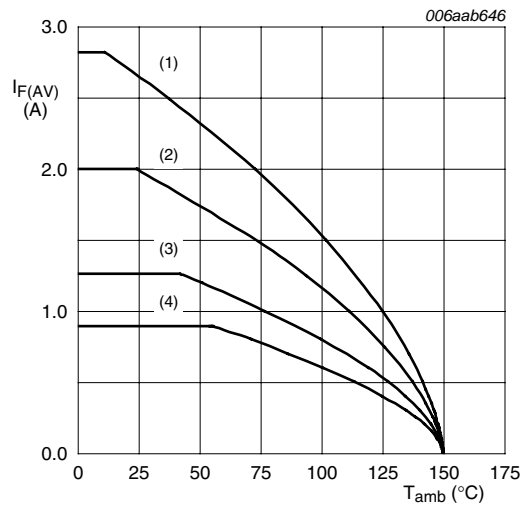


FR4 PCB, standard footprint

$T_j = 150\text{ °C}$

- (1)  $\delta = 1$ ; DC
- (2)  $\delta = 0.5$ ;  $f = 20\text{ kHz}$
- (3)  $\delta = 0.2$ ;  $f = 20\text{ kHz}$
- (4)  $\delta = 0.1$ ;  $f = 20\text{ kHz}$

**Fig 9. Average forward current as a function of ambient temperature; typical values**

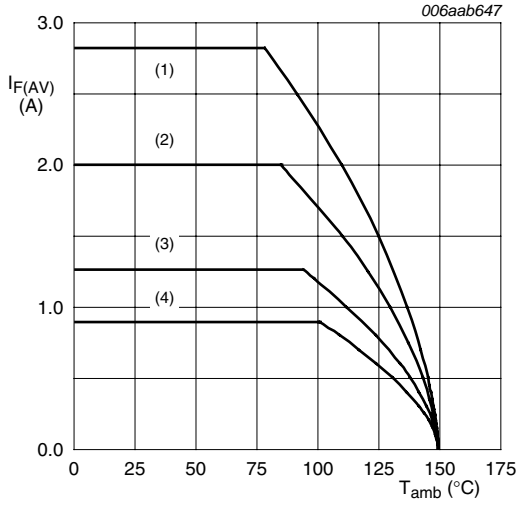


FR4 PCB, mounting pad for cathode  $1\text{ cm}^2$

$T_j = 150\text{ °C}$

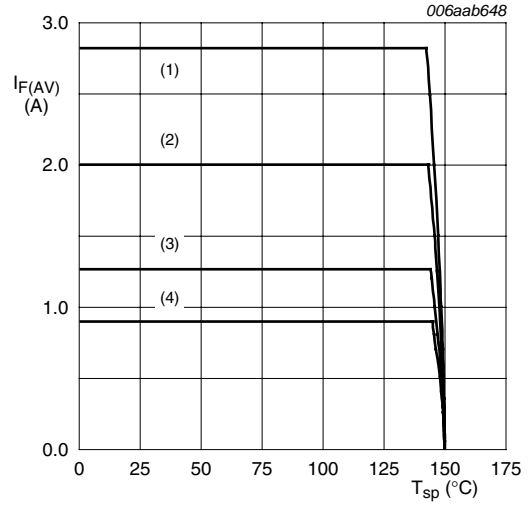
- (1)  $\delta = 1$ ; DC
- (2)  $\delta = 0.5$ ;  $f = 20\text{ kHz}$
- (3)  $\delta = 0.2$ ;  $f = 20\text{ kHz}$
- (4)  $\delta = 0.1$ ;  $f = 20\text{ kHz}$

**Fig 10. Average forward current as a function of ambient temperature; typical values**



Ceramic PCB,  $Al_2O_3$ , standard footprint  
 $T_j = 150$  °C  
 (1)  $\delta = 1$ ; DC  
 (2)  $\delta = 0.5$ ;  $f = 20$  kHz  
 (3)  $\delta = 0.2$ ;  $f = 20$  kHz  
 (4)  $\delta = 0.1$ ;  $f = 20$  kHz

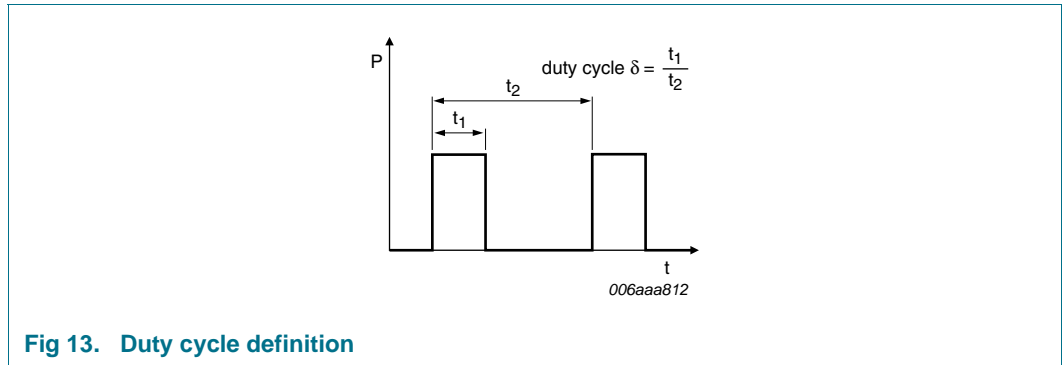
**Fig 11. Average forward current as a function of ambient temperature; typical values**



$T_j = 150$  °C  
 (1)  $\delta = 1$ ; DC  
 (2)  $\delta = 0.5$ ;  $f = 20$  kHz  
 (3)  $\delta = 0.2$ ;  $f = 20$  kHz  
 (4)  $\delta = 0.1$ ;  $f = 20$  kHz

**Fig 12. Average forward current as a function of solder point temperature; typical values**

## 8. Test information



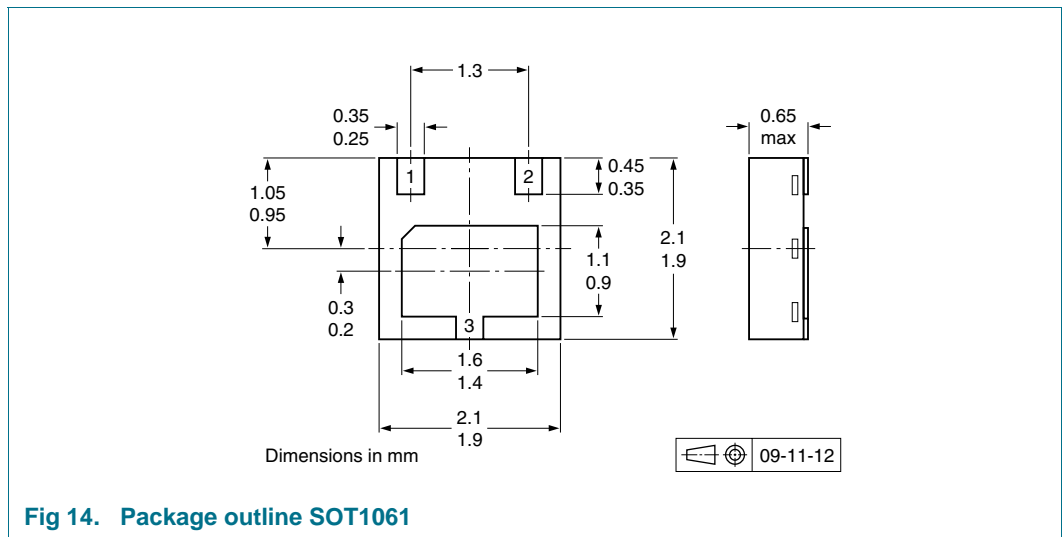
**Fig 13. Duty cycle definition**

The current ratings for the typical waveforms as shown in [Figure 9](#), [10](#), [11](#) and [12](#) are calculated according to the equations:  $I_{F(AV)} = I_M \times \delta$  with  $I_M$  defined as peak current,  $I_{RMS} = I_{F(AV)}$  at DC, and  $I_{RMS} = I_M \times \sqrt{\delta}$  with  $I_{RMS}$  defined as RMS current.

### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

## 9. Package outline



**Fig 14. Package outline SOT1061**

## 10. Packing information

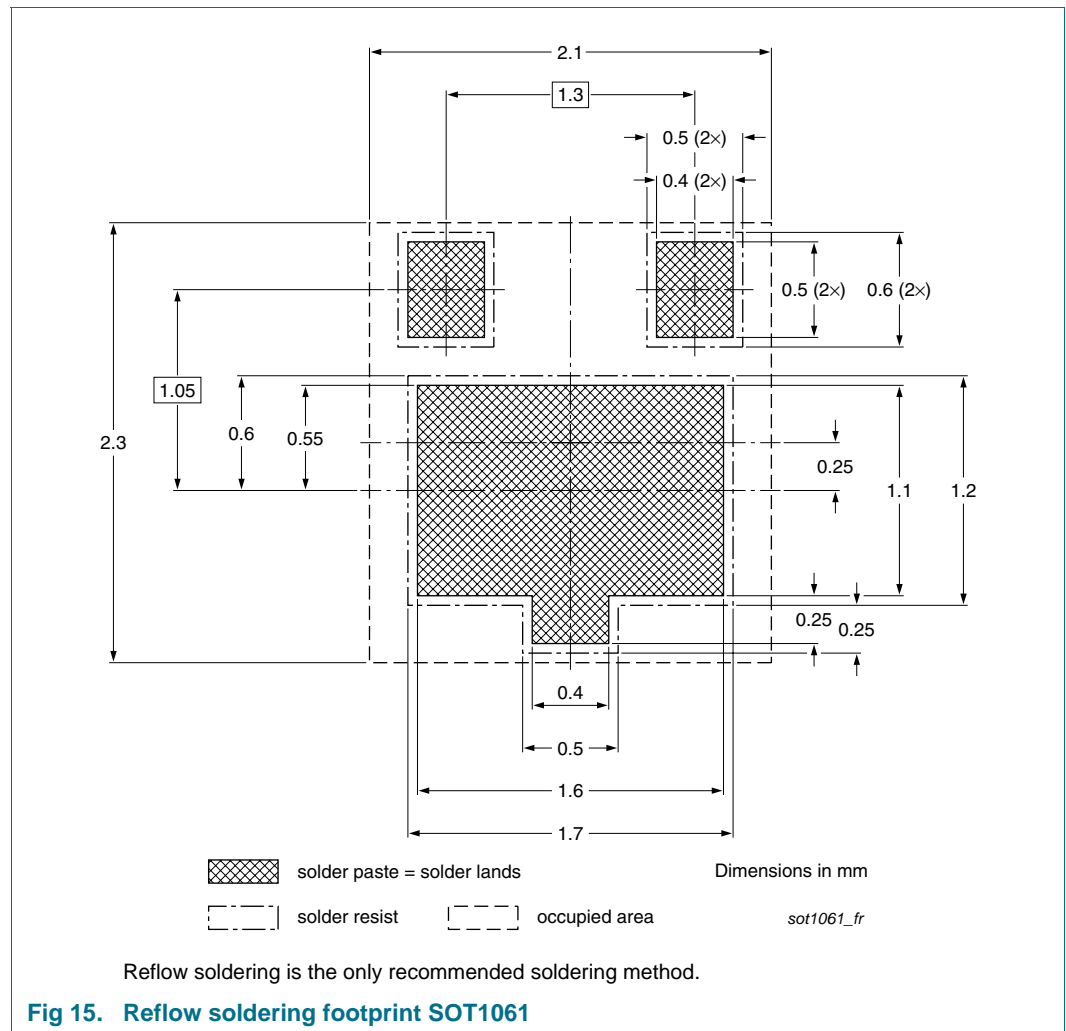
**Table 8. Packing methods**

The indicated -xxx are the last three digits of the 12NC ordering code.<sup>[1]</sup>

Type number	Package	Description	Packing quantity
			<b>3000</b>
PMEG3020EPA	SOT1061	4 mm pitch, 8 mm tape and reel	-115

[1] For further information and the availability of packing methods, see [Section 14](#).

## 11. Soldering



## 12. Revision history

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**Table 9.** Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PMEG3020EPA_1	20091215	Product data sheet	-	-

## 13. Legal information

### 13.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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